

$$C_{\pi}'=C_{\pi}+C_{\mu}'$$

$$C_{\mu} = C_{\mu} (1 - K)$$

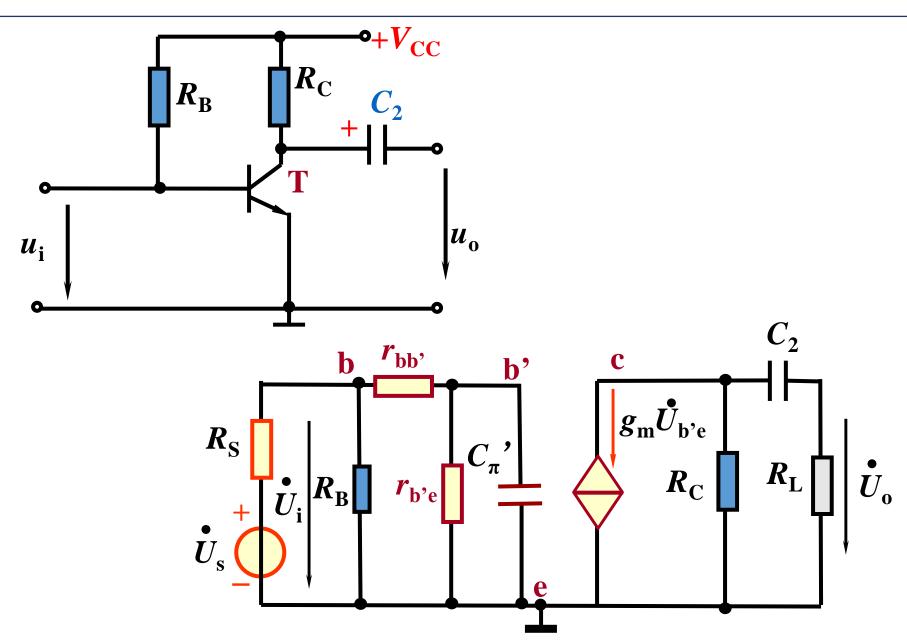
$$K = \frac{U_{ce}}{U_{be}}$$

$$f_{\beta} = \frac{1}{2\pi r_{\text{b'e}} (C_{\pi} + C_{\mu})}$$

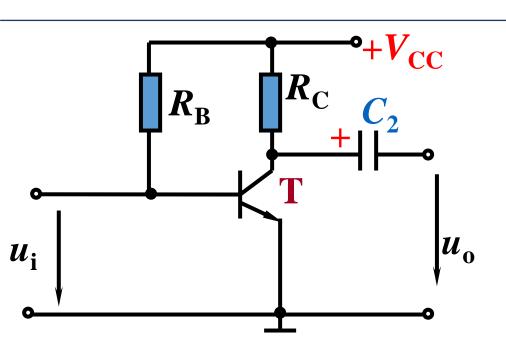
$$g_{\rm m} = \beta_0 \frac{1}{r_{\rm be}}$$

$$\approx \frac{I_{\rm E}}{U_{\rm T}}$$



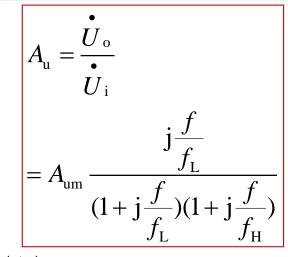


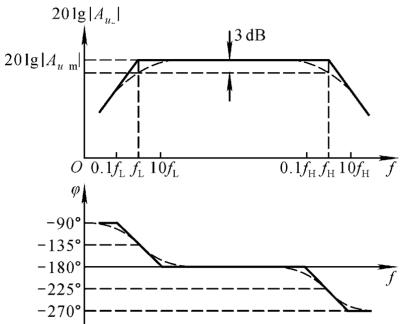




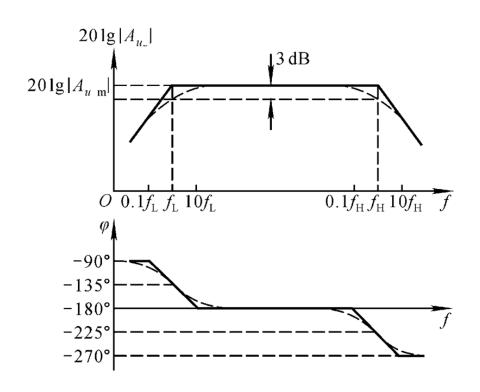
$$f_{\rm L} = \frac{1}{2\pi (R_{\rm C} + R_{\rm L})C_2} f_{\rm H} = \frac{1}{2\pi RC_{\pi}}$$

$$f_{\scriptscriptstyle \mathrm{BW}} = f_{\scriptscriptstyle \mathrm{H}} - f_{\scriptscriptstyle \mathrm{L}}$$





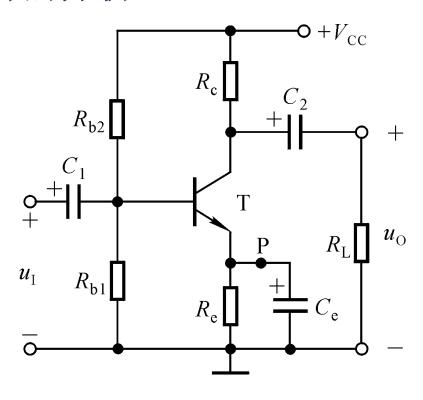




增益带宽积:
$$|A_{um}f_{BW}| \approx 常数$$

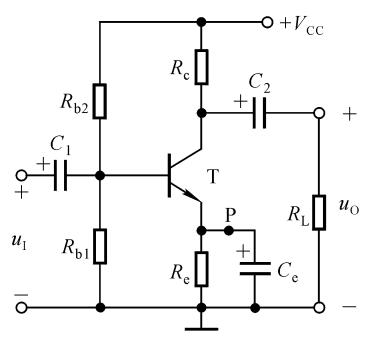


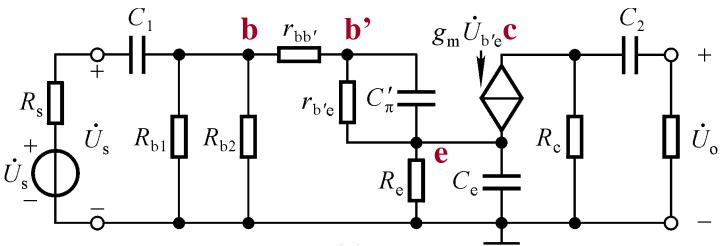
多个耦合电容的分析



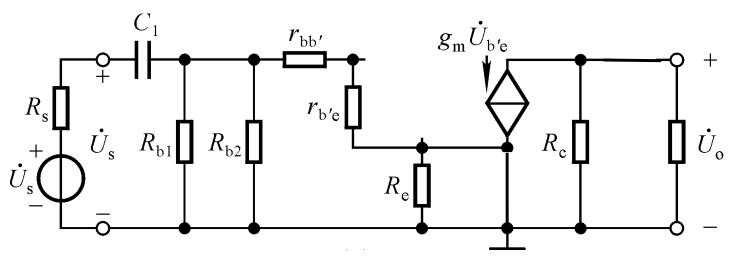
$$f_{\rm L1} = \frac{1}{2\pi R_1 C_1}$$
 $f_{\rm L2} = \frac{1}{2\pi R_2 C_2}$ $f_{\rm Le} = \frac{1}{2\pi R_3 C_{\rm e}}$

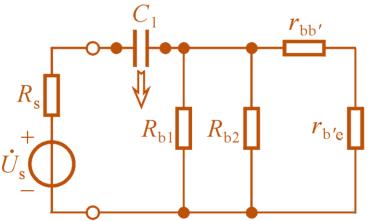










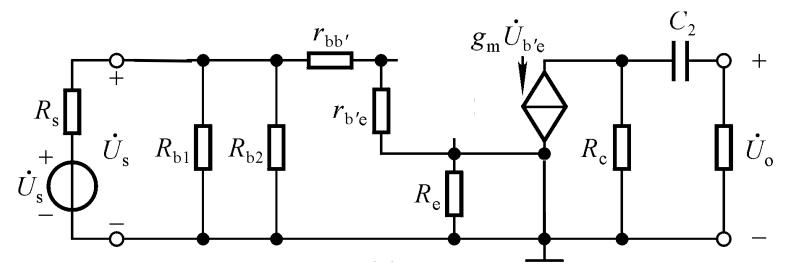


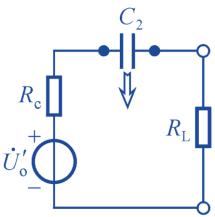
 C_2 、 C_e 短路, C_{π} 开路:

$$au_1 = (R_s + R_{b1} // R_{b2} // r_{be})C_1$$

$$f_{L1} = \frac{1}{2\pi\tau}$$





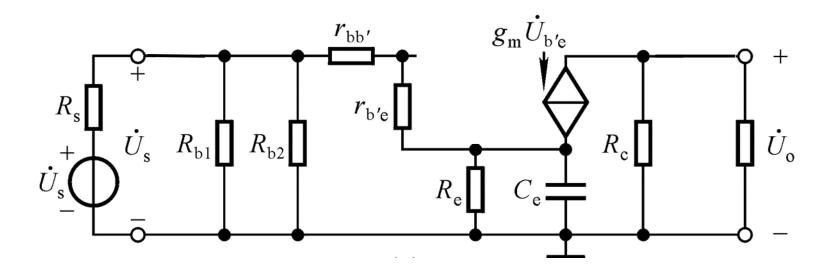


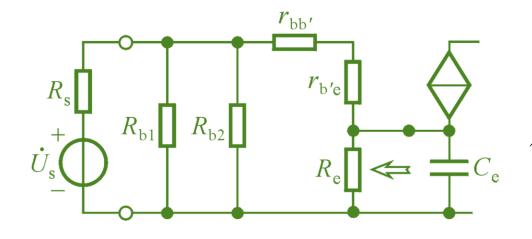
 C_1 、 C_e 短路, C_{π} 开路:

$$\tau_2 = (R_{\rm c} + R_{\rm L})C_2$$

$$f_{\rm L2} = \frac{1}{2\pi\tau_2}$$





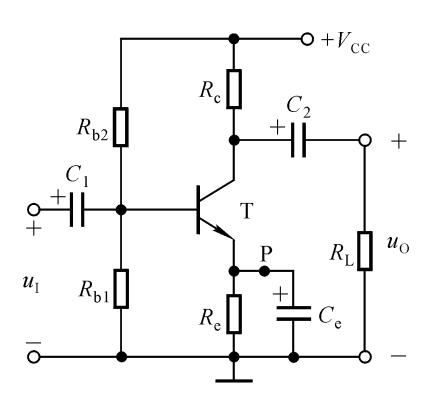


 C_1 、 C_2 短路, C_{π} 开路:

$$\tau_{\rm e} = (R_{\rm e} / / \frac{r_{\rm be} + R_{\rm s} / / R_{\rm b1} / / R_{\rm b2}}{1 + \beta}) C_{\rm e}$$

$$f_{\rm Le} = \frac{1}{2\pi\tau_{\rm e}}$$





$$f_{\rm L1} = \frac{1}{2\pi R_{\rm I} C_{\rm I}}$$

$$f_{\rm L2} = \frac{1}{2\pi R_2 C_2}$$

$$f_{\rm Le} = \frac{1}{2\pi R_3 C_{\rm e}}$$





$$A_{\rm u} = A_{\rm u1} \cdot A_{\rm u2} \cdot A_{\rm u3} \cdot \cdots \cdot A_{\rm un}$$

• 对数幅频特性和相频特性

$$20\lg|A_{u}| = 20\lg|A_{u1}| + 20\lg|A_{u2}| + \dots + 20\lg|A_{un}|$$

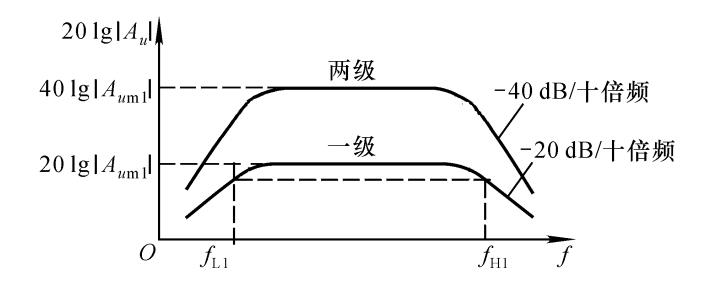
$$\varphi = \varphi_1 + \varphi_2 + \cdots + \varphi_n$$

电路的增益是各级放大电路增益之和,

相移是各级放大电路相移之和



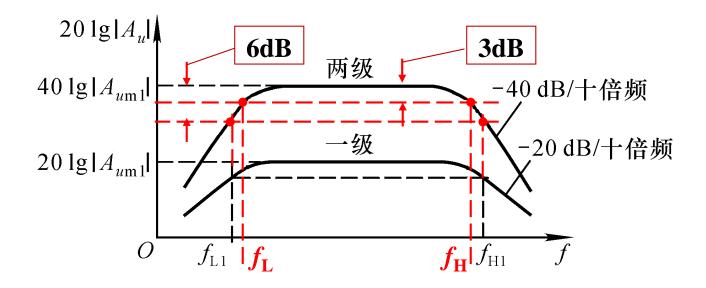
两级放大电路: $A_{u1}=A_{u2}$





两级放大电路: $A_{u1} = A_{u2}$

•注意—按照增益下降3dB计算截止频率和工作带宽





多级放大电路截止频率的估算

$$f_{\rm L} \approx 1.1 \sqrt{\sum_{k=1}^{n} f_{\rm L}^2}$$

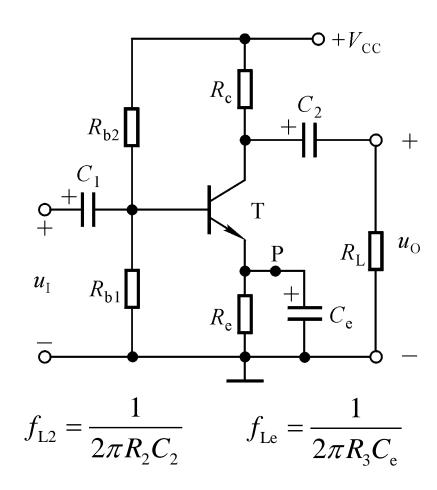
$$\frac{1}{f_{\rm H}} \approx 1.1 \sqrt{\sum_{k=1}^{n} \frac{1}{f_{\rm H}^2}}$$

多级放大电路的下截止频率升高、上截止频率降低、总工作频带变窄。

增益带宽积:
$$|A_{um}f_{BW}| \approx 常数$$



多个耦合电容



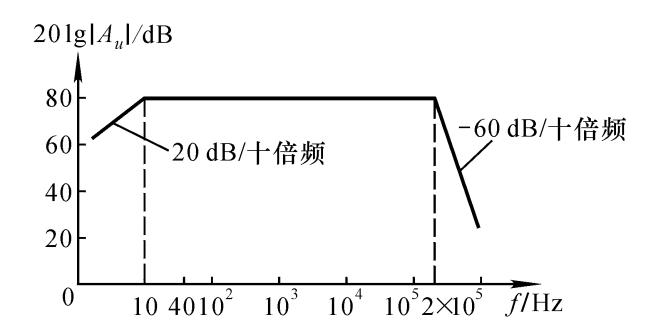
$$f_{\rm L1} = \frac{1}{2\pi R_1 C_1}$$

$$f_{\rm L} \approx 1.1 \sqrt{\sum_{k=1}^{n} f_{\rm Lk}^2}$$

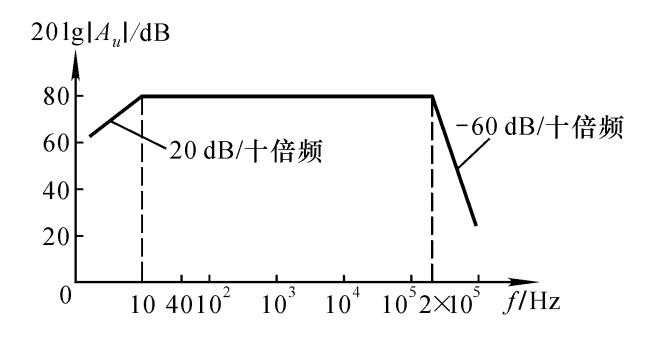


例: 已知某电路的各级均为共射放大电路,其幅频特性如图所

示,求下截止频率 $f_{
m L}$,上截止频率 $f_{
m H}$ 和电压放大倍数 $A_{
m u}$



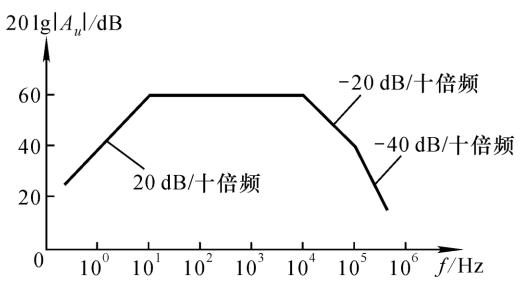




$$f_{\rm L}$$
=10Hz $f_{\rm H}$ =0.52×2×10⁵Hz=104kHz
$$A_{\rm u} = -10^4 \times \frac{j\frac{f}{10}}{(1+j\frac{f}{10})(1+j\frac{f}{10^5})^3}$$



例 某放大电路的波特图如图所示

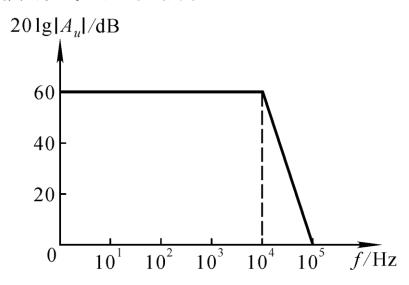


- (1) 电路的中频增益 $20\lg|A_{um}| = (60)dB$, $A_{um} = (\pm 10^3)$
- (2) 电路的下限频率 f_{L} = (10) Hz, 上限频率 f_{H} = (10⁴) Hz

(3)
$$A_{\rm u} = \pm 10^3 \times \frac{j\frac{f}{10}}{(1+j\frac{f}{10})(1+j\frac{f}{10^4})(1+j\frac{f}{10^5})}$$



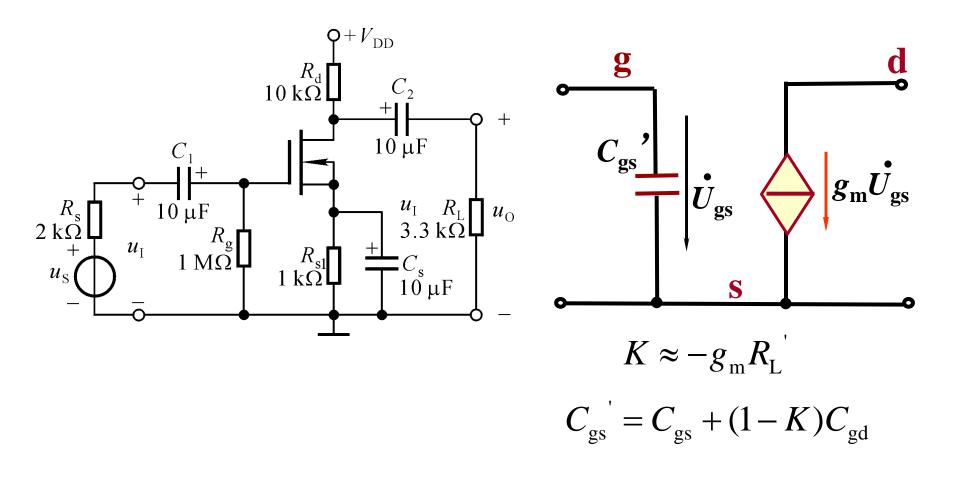
例 已知某电路的幅频特性如图所示



- (1) 该电路的耦合方式? 下限截止频率为0, 直接耦合电路;
- (2) 该电路由几级放大电路组成? 三级放大电路
- (3) 当 $f=10^4$ Hz时,附加相移是多少? $\varphi'=-135^\circ$ 当 $f=10^5$ Hz时,附加相移又是多少? $\varphi'\approx-270^\circ$
- (4) 该电路的上限频率 f_H 约为多少? $f \approx 0.52f_1 \approx 5.2 \text{k Hz}$

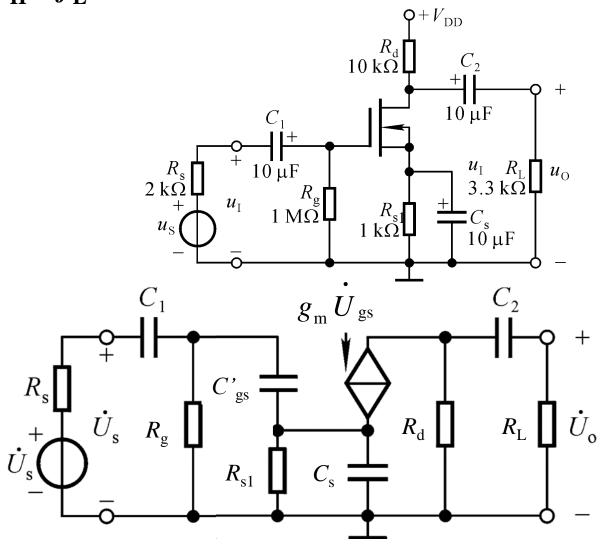


例:已知 $C_{gs}=C_{gd}=5$ pF, $g_{m}=5$ mS, $C_{1}=C_{2}=C_{S}=10$ μ F。 试求出 f_{H} , f_{L} 各约多少。



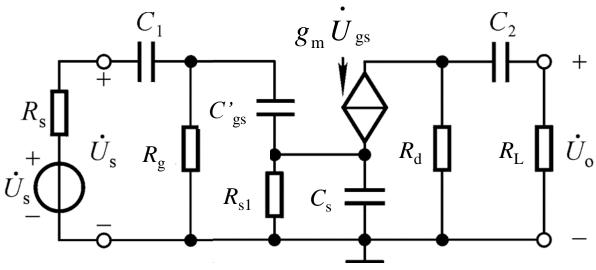


已知 $C_{gs}=C_{gd}=5$ pF, $g_{m}=5$ mS, $C_{1}=C_{2}=C_{S}=10$ μ F。试求出 f_{H} , f_{L} 各约多少。





已知 $C_{gs} = C_{gd} = 5$ pF, $g_m = 5$ mS, $C_1 = C_2 = C_S = 10$ µF。试求出 f_H , f_L 各约多少,并写出 A_{us} 的表达式



$$C_{\rm gs}' = C_{\rm gs} + (1 - K)C_{\rm gd}$$

$$K = -g_{\rm m}R_{\rm L} = -12.4$$

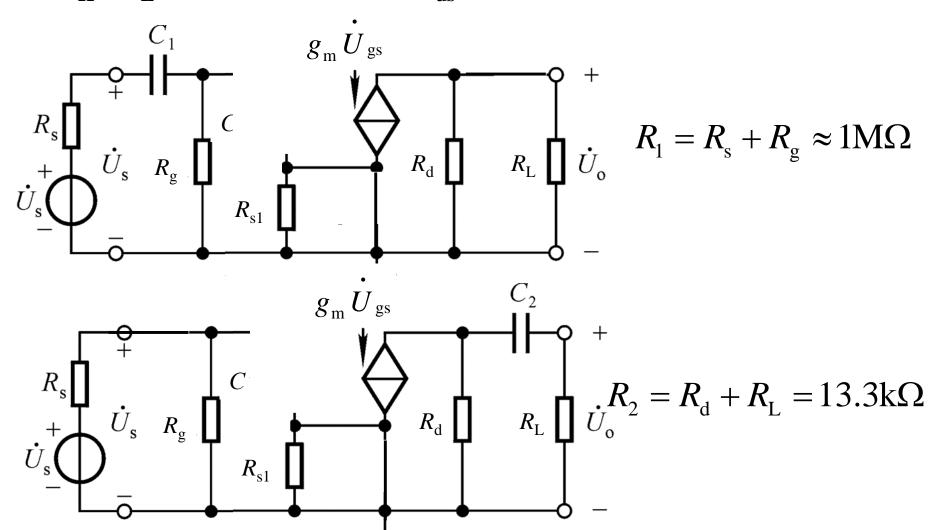
$$C_{gs} = C_{gs} + (1 - K)C_{gd} = 72pF$$

$$R_{\rm gs}' = R_{\rm s} / / R_{\rm g} \approx R_{\rm s}$$

$$f_{\rm H} = \frac{1}{2\pi R C'}$$

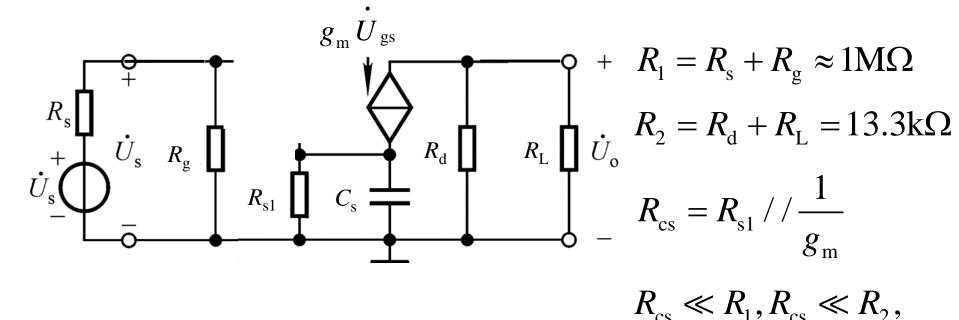


已知 $C_{gs}=C_{gd}=5$ pF, $g_{m}=5$ mS, $C_{1}=C_{2}=C_{S}=10$ µF。试求出 f_{H} , f_{L} 各约多少,并写出 A_{us} 的表达式





已知 $C_{gs} = C_{gd} = 5$ pF, $g_m = 5$ mS, $C_1 = C_2 = C_S = 10$ µF。试求出 f_H , f_L 各约多少,并写出 A_{us} 的表达式



$$f_{\rm L} = \frac{1}{2\pi R_{\rm cs} C_s}$$
 $f_{\rm H} = \frac{1}{2\pi R_{\rm s} C_{gs}}$



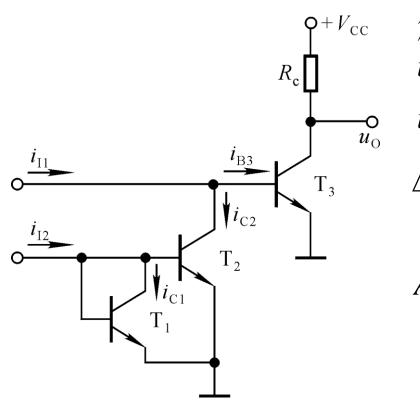
作业

- 4.3
- 4.6
- 4.12
- 4.13



习题3.16已知 $T_1 \sim T_3$ 管的特性完全相同, $\beta > > 2$,反相输入端的输入电流为 i_{I1} ,同相输入端的输入电流为 i_{I2} 。试问:

(1)
$$i_{C2}\approx ?$$
 (2) $i_{B3}\approx ?$ (3) $A_{ui}=\Delta u_{O}/\Delta (i_{I1}-i_{I2})\approx ?$



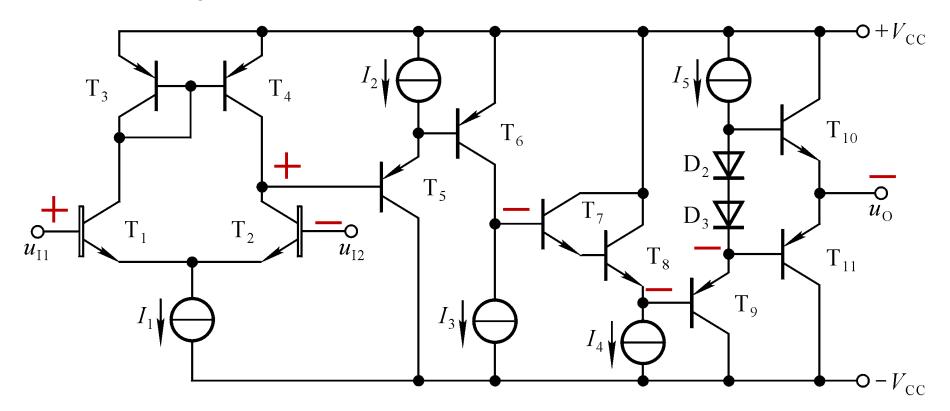
 $mathred E : T_1和T_2为镜像关系,<math>i_{C2} \approx i_{C1} \approx i_{I2}$ $i_{B3} = i_{I1} - i_{C2} \approx i_{I1} - i_{I2}$ $\Delta u_{O} = -\Delta i_{C3} R_{c} = -\beta_{3} \Delta i_{B3} R_{c}$ $= -\beta_{3} \Delta (i_{I1} - i_{I2}) R_{c}$

$$A_{ui} = \Delta u_{\rm O} / \Delta (i_{\rm I1} - i_{\rm I2}) = -\beta_3 R_{\rm c}$$



习题3.18(1)两个输入端中哪个是同相输入端,哪个是反相输入端;

- (2) T₃与T₄的作用;
- (3) 电流源 I_3 的作用;
- (4) D_2 与 D_3 的作用





电路如图所示, T_1 与 T_2 管的特性相同,所有晶体管的 β 均相同, R_{c1} 远大于二极管的正向电阻。当 $u_{I1}=u_{I2}=0$ V时, $u_0=0$ V。求解

- (1) 电压放大倍数的表达式
 - (2) 有共模输入电压时, u_o=? 简述理由

